



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



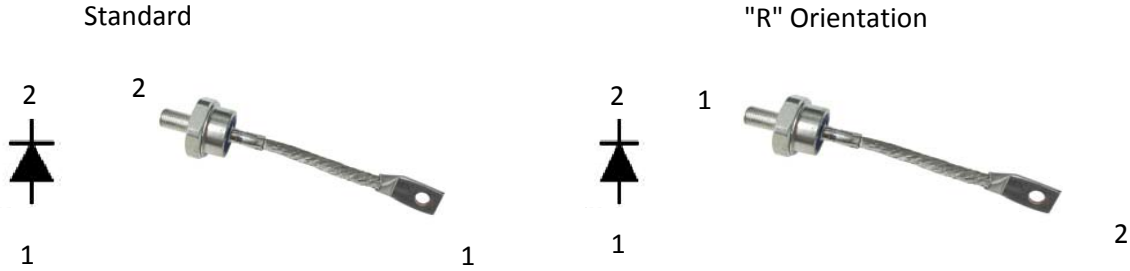
Silicon Standard Recovery Diode

$V_{RRM} = 200\text{ V} - 1000\text{ V}$
 $I_F = 150\text{ A}$

Features

- High Surge Capability
- Types up to 1000 V V_{RRM}

DO-8 Package



Maximum ratings, at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	150K(R)20A	150K(R)40A	150K(R)60A	150K(R)80A	150K(R)100A	Unit
Repetitive peak reverse voltage	V_{RRM}		200	400	600	800	1000	V
DC blocking voltage	V_{DC}		200	400	600	800	1000	V
Continuous forward current	I_F	$T_C \leq 110\text{ }^\circ\text{C}$	150	150	150	150	150	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ }^\circ\text{C}$, $t_p = 8.3\text{ ms}$	3740	3740	3740	3740	3740	A
I_2t for fusing	I_2t	$t = 8.3\text{ms}$	58000	58000	58000	58000	58000	A^2sec
Operating temperature	T_j		-40 to 200	-40 to 200	-40 to 200	-40 to 200	-40 to 200	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to 200	-40 to 200	-40 to 200	-40 to 200	-40 to 200	$^\circ\text{C}$

Electrical characteristics, at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	150K(R)20A	150K(R)40A	150K(R)60A	150K(R)80A	150K(R)100A	Unit
Diode forward voltage	V_F	$I_F = 150\text{ A}$, $T_j = 25\text{ }^\circ\text{C}$	1.33	1.33	1.33	1.33	1.33	V
Reverse current	I_R	$V_R = V_{RRM}$, $T_j = 175\text{ }^\circ\text{C}$	35	35	35	32	24	mA

Thermal characteristics

Thermal resistance, junction - case	R_{thJC}		0.25	0.25	0.25	0.25	0.25	$^\circ\text{C/W}$
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